NSN 5962-01-344-0904

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View Online at https://aerobasegroup.com/nsn/5962-01-344-0904

Overall Length:

Between 0.540 inches and 0.560 inches

Overall Height:

Between 0.060 inches and 0.120 inches

Overall Width:

Between 0.442 inches and 0.458 inches

Body Length:

Between 0.540 inches and 0.560 inches

Body Width:

Between 0.442 inches and 0.458 inches

Body Height:

Between 0.060 inches and 0.120 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

W/disable and monolithic and bidirectional

Inclosure Material:

Ceramic

Inclosure Configuration:

Leadless flat pack

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

26 input

Case Outline Source And Designator:

C-12 mil-m-38510

Current Rating Per Characteristic:

150.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Product Name:

Sram

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Capitance Rating Per Characteristic:

Err-060 and err-060

Time Rating Per Chacteristic:

45.00 nanoseconds af output megawatts

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A458a0



Memory Device Type:
Ram
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
32 leadless
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig: